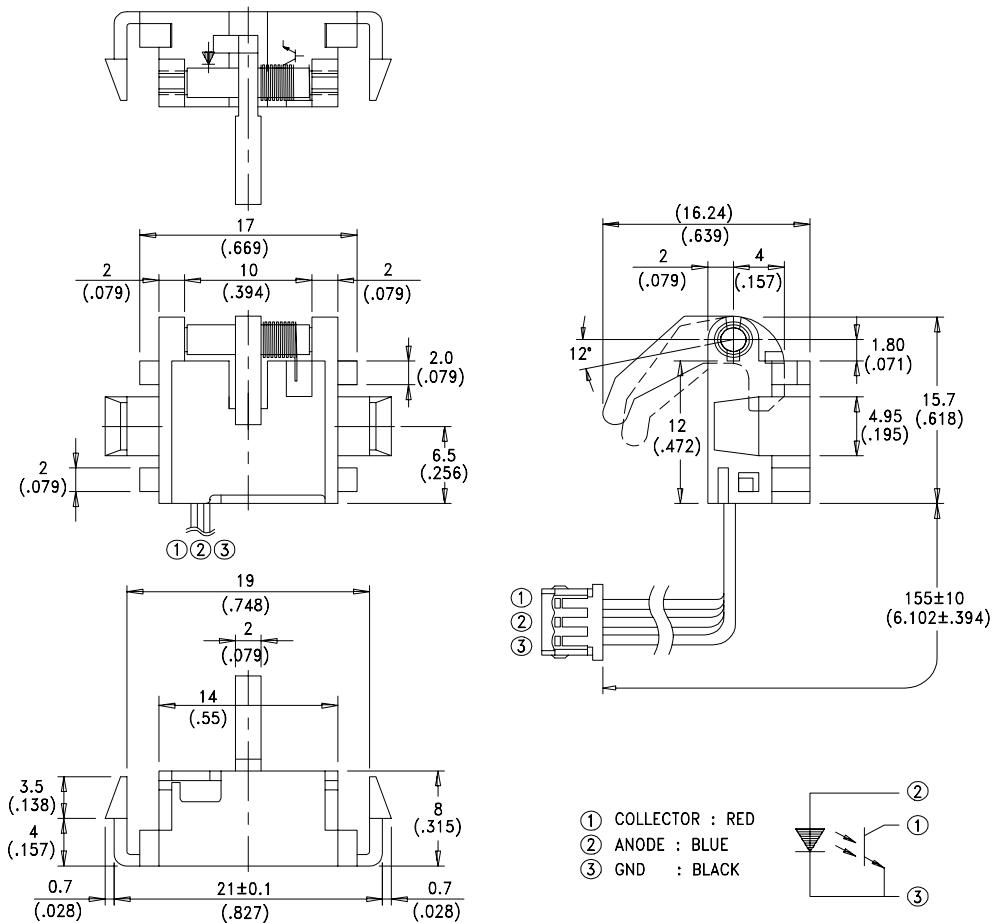


FEATURES

- * SNAP MOUNTING.
- * MECHANICAL SWITCH REPLACEMENT.
- * THREE WIRES FOR ELECTRICAL CONNECTION.
- * CUSTOMIZED LEVER ARM CAN BE DESIGNED FOR SPECIFIC APPLICATION.

PACKAGE DIMENSIONS**NOTES:**

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25\text{mm} (.010")$ unless otherwise noted.

ABSOLUTE MAXIMUM RATINGS AT TA=25°C

PARAMETER	MAXIMUM RATING	UNIT
IR Diode Continuous Forward Current	50	mA
IR Diode Reverse Voltage	5	V
Transistor Collector Current	20	mA
Transistor Power Dissipation	75	mW
IR Diode Peak Forward Current (Pulse Width = 10 μ S, 300 pps)	1	A
Diode Power Dissipation	60	mW
Phototransistor Collector-Emitter Voltage	30	V
Phototransistor Emitter-Collector Voltage	5	V
Operating Temperature Range	-25°C to +85°C	
Storage Temperature Range	-55°C to +100°C	

ELECTRICAL OPTICAL CHARACTERISTICS AT TA=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
INPUT LED						
Forward Voltage	VF		1.2	1.6	V	IF = 20mA
Reverse Current	IR			100	μ A	VR=5V
OUTPUT PHOTOTRANSISTOR						
Collector-Emitter Breakdown Voltage	V(BR)CEO	30			V	IC=1mA
Emitter-Collector Breakdown Voltage	V(BR)ECO	5			V	IE=100 μ A
Collector-Emitter Dark Current	ICEO			100	nA	VCE=10V
COUPLER						
Collector-Emitter Saturation Voltage	VCE(SAT)			0.4	V	IC=0.2mA IF=20mA
On State Collector Current	Ic(ON)	0.5	2		mA	VCE=5V IF=20mA

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTICS CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

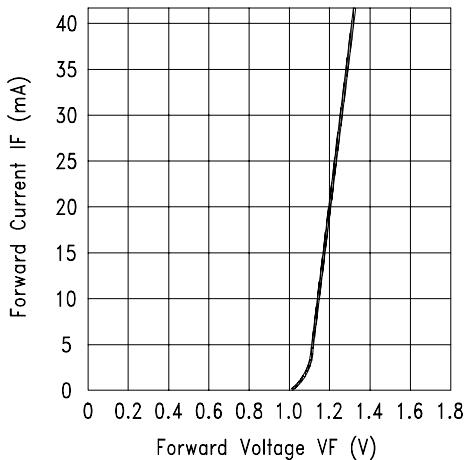


Fig.1 FORWARD CURRENT VS.
FORWARD VOLTAGE

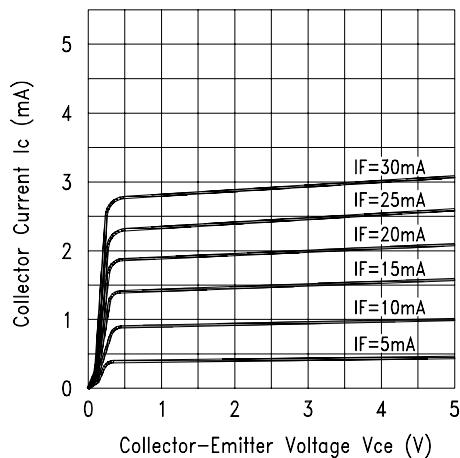


Fig.2 COLLECTOR CURRENT VS.
COLLECTOR VOLTAGE

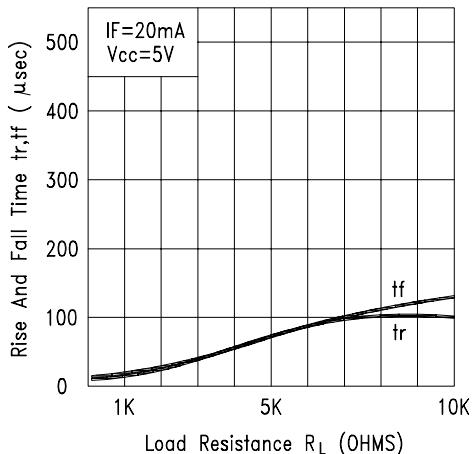


Fig.3 RISE AND FALL TIME VS.
LOAD RESISTANCE

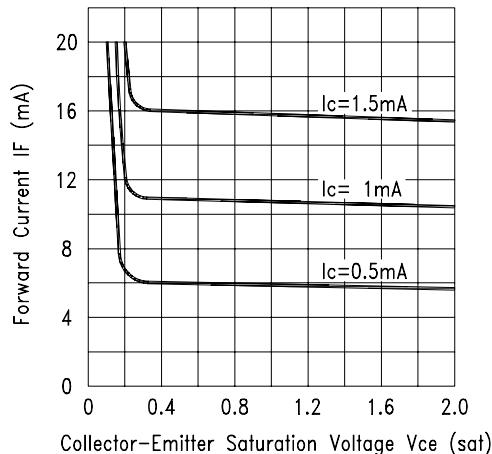


Fig.4 FORWARD CURRENT VS.
Collector-Emitter Saturation Voltage